



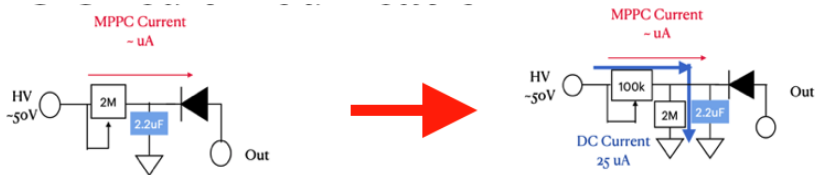
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LAMPS ToF Progress

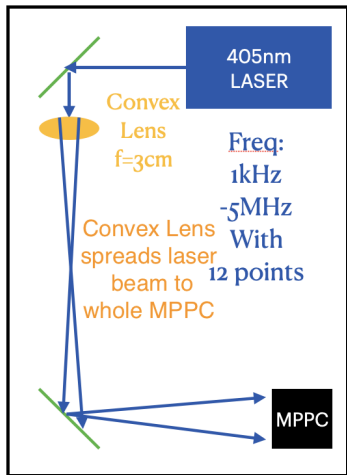
August 20, 2021

New ToF Circuit test



- Benefits from this modification: Gain-drop on signal frequency is reduced.
- Voltage-Control: ~ 2 V
- Gain drop vs Frequency with new circuit were tested.
- Pulse shape seemed fine, gain-control was good.

Gaindrop-frequency test



Gain-Frequency relation

$$I = I_{base} + Gain \times freq \quad (1)$$

$$Gain = g(HV - R \times I) \quad (2)$$

$$Gain = g \frac{HV - R \times I_{base}}{1 + gR \times freq} \quad (3)$$
$$= g \frac{HV - R \times I_{base}}{1 + f/f_{HDF}}$$

- MPPC gain has liner dependence on applied voltage.
- This equaiton assumes flat photon distribution for all identical MPPCs.

Result

Half-Drop Frequency	BTOF	FTOFin	FTOFOut
MIP	3MHz	10MHz	10MHz
Saturation	0.5MHz	0.9MHz	1.2MHz

- Saturation region is around MHz/Segment.
- BTOF/FTOFOut covers wide-region, so Photon distribution was not flat.(Only half of MPPCs were hit.)

MPPC Gain Check.

$$I_{MPPC} = I_{photon} * N_{photon} / N_{MPPC} \quad (4)$$

$$= V_{drop} / R_{trim} = 40\mu A = 2.5 \times 10^{14} e/s. \quad (5)$$

Known parameters: $R_{trim} = 50k$, $V_{drop} \simeq 2 V$ at f_{HDR} , $N_{MPPC} \simeq 3$.

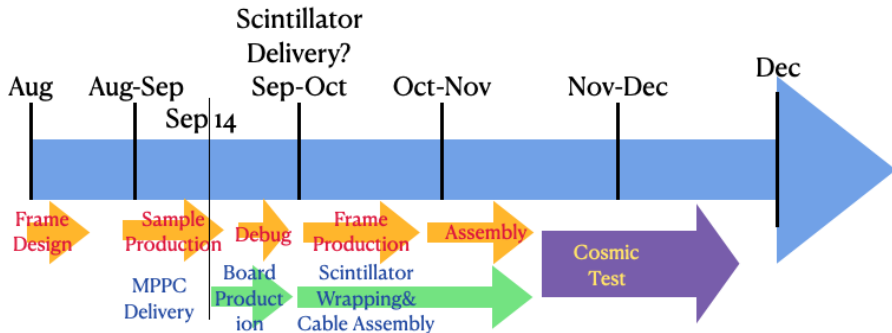
Photon Estimation

$$\frac{N_{\text{Photon}}}{N_{\text{mppc}}} = \frac{1}{N_{\text{mppc}}} \frac{G_{\text{sig}}}{G_{\text{photon}}}$$

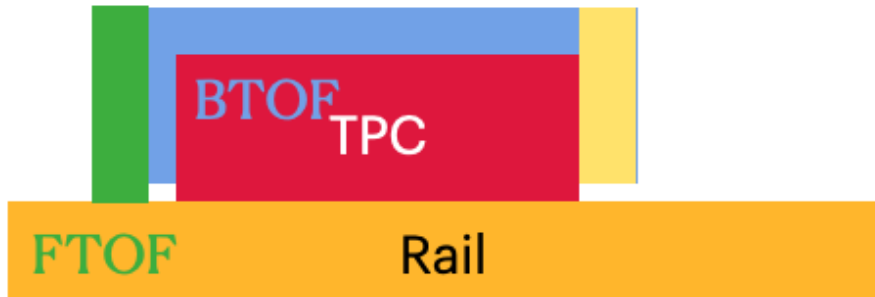
# Photons	BTOF	FTOF
MIP	30/MPPC	3/MPPC
Saturate	200/MPPC	100/MPPC
$f_{\text{PhotonHDF}}$	$\sim 100\text{MHz}$	$\sim 100\text{MHz}$
$\text{Gain}_{\text{MPPC}}$	$\frac{3.75 \times 10^{14} \text{ e/s}}{100\text{MHz}} = 2.5 \times 10^6$	

- $f_{\text{PhotonHDF}}$ is based on saturation data.

ToF Schedule

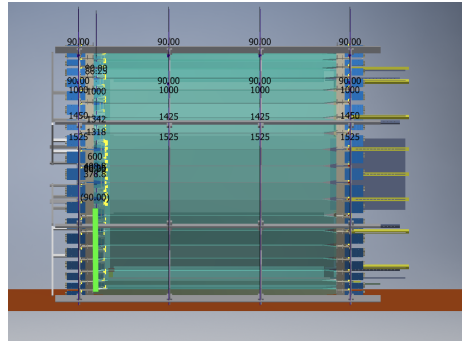
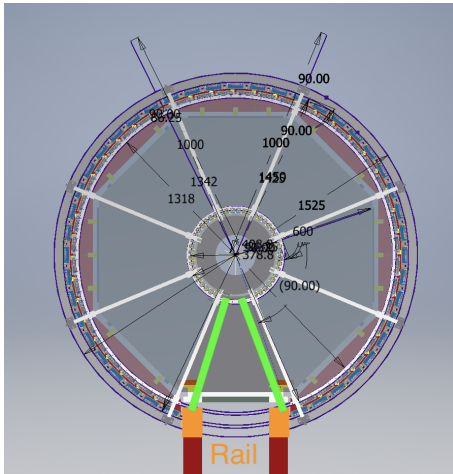


Frame Design Concept



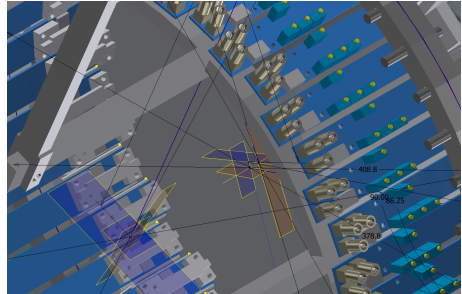
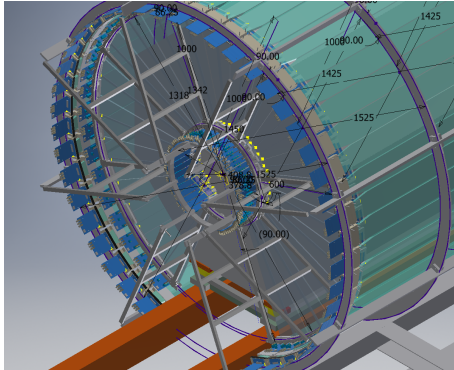
- TPC and FTOF supports BTOF
- FTOF is supported by rail

FTOF Support



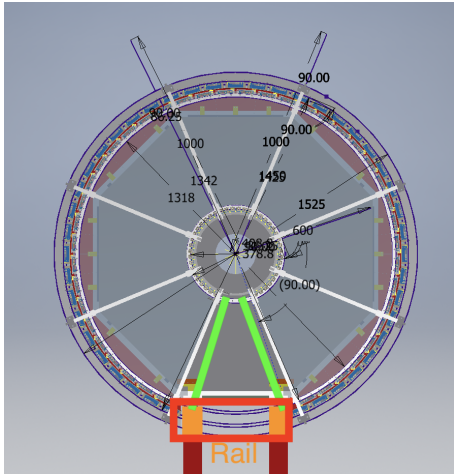
- FTOF is supported by two legs on the Rail.

FTOF Board Protection



- Supporting structure prevents FTOF detachment while inserting LEMO.

Loss-region



- Around 1/8 region cannot be covered by TOFs, due to support structure

BACKUP

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MPPC Gain at Specsheat

S13360-1350CS	Vover =3 V	270 to 900
S13360-1350PE		320 to 900
S13360-3050CS		270 to 900
S13360-3050PE		320 to 900
S13360-6050CS		270 to 900
S13360-6050PE		320 to 900

450

40	90	270	60	1.7×10^6	53 ± 5
	500	1500	320		
	2000	6000	1280		

Electrical and optical characteristics (Typ. Ta=25 °C, Vover=2.7 V, unless otherwise noted)

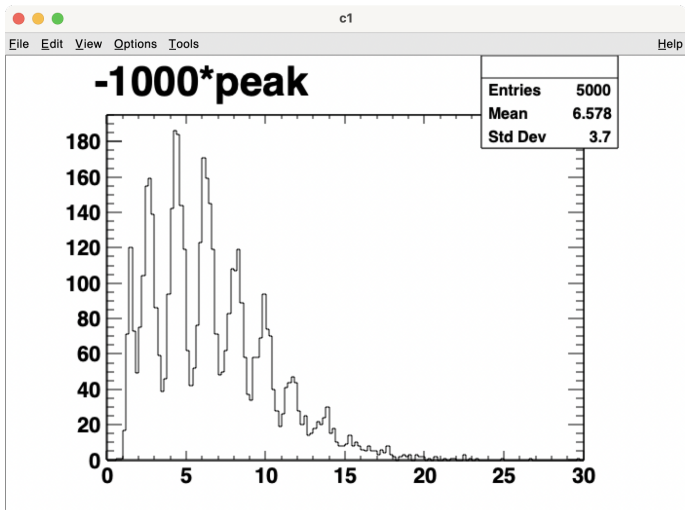
Parameter	Symbol	S14160/S14161 -3050HS-04, -08	S14160/S14161 -4050HS-06	S14160/S14161 -6050HS-04	unit
Spectral response range	λ	270 to 900			nm
Peak sensitivity wavelength	λ_p	450			nm
Photon detection efficiency at λ_p ^{*3}	PDE	50			%
Breakdown voltage	VBR	38			V
Recommended operating voltage ^{*4}	Vop	VBR + 2.7			V
Vop variation between channels in one product ^{*5}	Typ.	0.1			V
	Max.	0.2			
Dark current	Typ.	0.6	1.1	2.5	μA
	Max.	1.8	3.3	7.5	
Crosstalk probability	-	7			%
Terminal capacitance	Ct	500	900	2000	pF
Gain	M	2.5×10^6			-
Temperature coefficient of recommended reverse voltage	ΔT_{Vop}	34			mV/°C

*3: Photon detection efficiency does not include crosstalk and afterpulses.

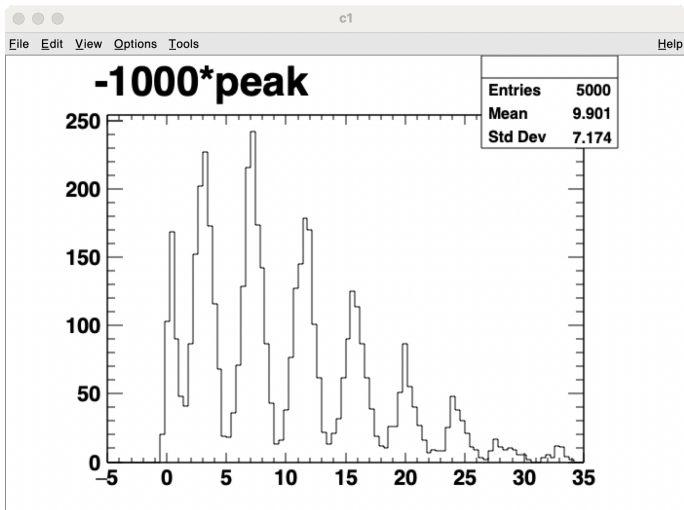
*4: Refer to the data attached for each product.

*5: The parameter is for the S14161 series (multichannel type)

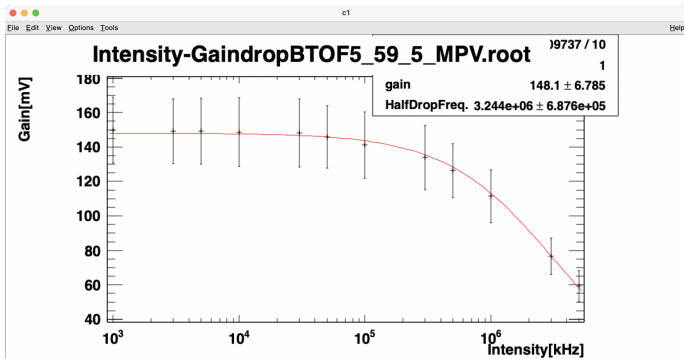
BTOFPhoton



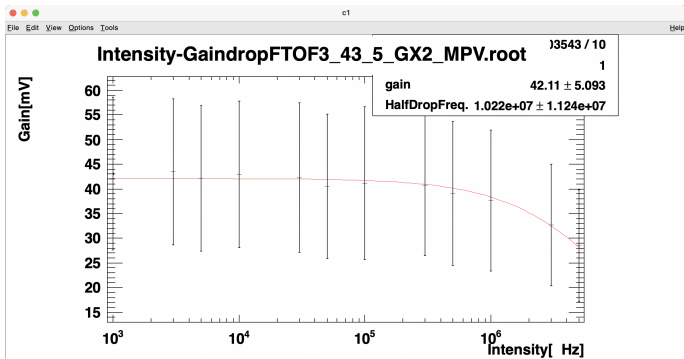
FTOFPhoton



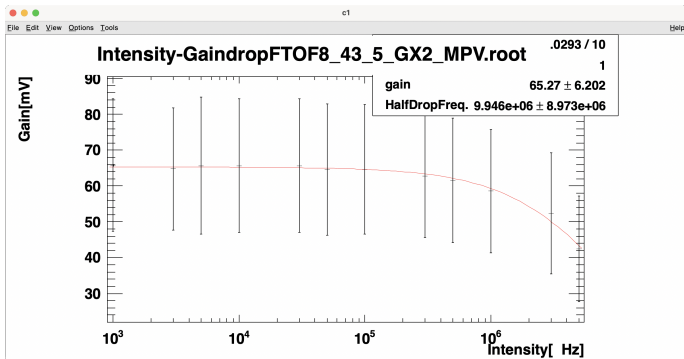
BTOFMIP



FTOFInMIP



FTOFOutMIP



BTOFSat

